00-718 3/9EET 1 OF

FÖRM PTO-1449

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTORNEY DOCKET NO. 4704/USA/ETCH/SILICON

SERIAL NO.:

LIST OF ART CITED BY APPLICANT

(Use several sheets if necessary)

FILING DATE: Herewith

GROUP: Uni

	<u></u>	,	<b>.</b>	W=:			······································	. 1 2	U.S.	PATENT D	OCUMENTS			
Examiner Initial					DOC	KET NU	JMBER			DATE 08/04/81	NAME Kûyel	CLASS 427	SUBCLASS 38	FILING . IF APPROPRIATE
		Al	4	2	8	2	2	6	7					
<u>U</u>	70	A2	4	4	3	3	2	2	8	02/21/84	Nishimatsu, et al.	219	10.55 R	
		A3	4	4	6	5	5	3	2	08/14/84	Fukano	156	643	
		A4	4	4	9	0	2	0	9	12/25/84	Hartman	156	643	
		A5	4	5	0	2	9	1	4	03/05/85	Trumpp et al.	156	643	
		A6	4	5	7	6	6	9	2	03/18/86	Fukuta, et al.	204	165	
		A7	4	7	0	5	5	9	5	11/10/87	Okudaira et al.	156	643	
		A8	4	7	3	8	7	4	8	04/19/88	Kisa	156	643	
		A9	4	7	8	6	3	5	2	11/22/88	Benzing	156	345	<del></del>
·		A10	4	8	1	8	3	2	6	04/04/89	Liu, et al.	156	345	
		A11	4	8	3	1	9	6	3	05/23/89	Saito, et al.	118	723	
		A12	4	8	6	3	5	6	1	09/05/89	Freeman, et al.	156	646	
		A13	4	8	6	7	8	4	1	09/19/89	Loewenstein, et al.	156	643	
		A14	4	8	7	6	2	1	2	10/24/89	Koury	437	34	
	$\top$	Ī				T		T	1					

APPLICANT: Yuen et al.

12/04/90 Yamazaki, et al. 156 643 A15 A16 6 02/12/91 Tachi et al. 156 643 9 9 0 02/19/91 Sun et al. 437 192 A17 5 0 3 03/26/91 Loewenstein, et al. 643 A18 0 2 2 156 6 5 05/07/91 A19 3 ٠3 8 156 643 Long et al. A20 5 0 3 5 7 6 8 07/30/91 Mu et al. 156 626 5 01/28/92 McKee A21 0 8 6 156 345 A22 5 03/10/92 Becker et al. 156 643 156 05/05/92 A23 Fujii et al. 5 05/05/92 0 A24 156 656 Long 8 06/02/92 5 8 3 7 Kadomura 156 657 A25 8 10/27/92 156 643 A26 Cheung, et al. 5 0 6 0 7 11/03/92 Latchford et al. A27 156 656 5 11/17/92 3 A28 4 3 Davis et al. 437 192 6 5 9 6 7 01/05/93 A29 7 Fullowan et al. 156 652 02/23/93 A30 437 193 Lai 5 03/09/93 A31 2 437 47 Tseng

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

**DATE CONSIDERED** 



(19-7183 FG 3 OF 5

SERIAL NO.: N/A ATTORNEY DOCKET NO. 4704/USA/ETCH/SILICON U.S. DEPARTMENT OF COMMERCE FORM PTO-1449 PATENT AND TRADEMARK OFFICE APPLICANT: Yuen et al. LIST OF ART CITED BY APPLICANT FILING DATE: Herewith (Use several sheets if necessary) FOREIGN PATENT DOCUMENTS TRANSLATION **SUBCLASS CLASS** COUNTRY DATE DOCKET NUMBER NO YES **EP Application** 06/22/88 3 2 0 Bl **EP Application** 05/10/89 0 3 0 B2 EP Application 01/02/92 3 6 3 3 **B**3 EP Application 12/02/92 3 6 5 0 **B4 EP Application** 08/18/93 6 5 5 5 0 **B**5 EP Application 02/21/96 7 6 7 4 9 B6 EP Application 12/04/96 5 0 7 B7 German Application 04/08/93 5 5 2 3 **B**8 PCT 05/23/96 5 5 5 6 B9 Japan 06/24/94 9 B10 Japan 01/31/95 9 0 B11 DATE CONSIDERED 10-021 Goudrem cord EXAMINER

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

FORM PTO-1449

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE ATTORNEY DOCKET NO. 4704/USA/ETCH/SILICON

SERIAL NO.: N/A

LIST OF ART CITED BY APPLICANT

(Use several sheets if necessary)

APPLICANT: Yuen et al. FILING DATE: Herewith

GROUP: Unknown

	U.S. PATENT DOCUMENTS												
Examiner Initial				DOCI	KET NU	MBER			DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
apply	A32	5	2	5	6	2	4	5	10/26/93	Keller, et al.	156	643	
070	A33	5	2	8	1	3	0	2	01/25/94	Gabric, et al.	156	643	
	A34	5	2	8	2	8	9	9	02/01/94	Balmashonov, et al.	118	723 R	
	A35	5	3	1	2	5	1	9	05/17/94	Sakai, et al.	134	1	
	A36	5	3	1	8	6	6	8	06/07/94	Tamaki, et al.	156	662	
	A37	5	3	3	8	3	9	8	08/16/94	Szwejkowski, et al.	156	655	
	A38	5	3	5	4	4	1	7	10/11/94	Cheung, et al.	156	643	
	A39	5	3	5	6	4	7	8	10/18/94	Chen, et al.	134	1	
	A40	5	3	5	8	6	0	1	10/25/94	Cathey	156	656	
	A41	5	3	7	8	3	1	1	01/03/95	Nagayama, et al.	156	643	
	A42	5	3	8	2	3	1	6	01/17/95	Hills, et al.	156	643	
	A43	5	4	1	3	9	5	4	05/09/95	Aydil, et al.	437	81	
	A44	5	4	3	1	7	7_	2	07/11/95	Babie, et al.	156	643.1	
	A45	5	4	4	3	6	8	6	08/22/95	Jones, et al.	216	37	
	A46	5	4	4	9	4	1	l	09/12/95	Fukuda, et al.	118	723 MP	
	A47	5	5	1	4	6	2	2	05/07/96	Bornstein, et al.	437	189	
	A48	5	5	2	1	1	1	9	05/28/96	Chen, et al.	437	187	
	A49	5	5	2	9	1	9	7	06/25/96	Grewal	216	68	
	A50	5	6	2	0	6	1	5	04/15/97	Keller	438	720	
	A51	5	6	2	6	7	7	5	05/06/97	Roberts, et al.	216	67	
	A52	5	6	4	4	l	5	3	07/01/97	Keller	257	324	
	A53	5	7	5	3	5	3	3	05/19/98	Saito	437	192	
	A54	5	7	5	6	4	0	0	05/26/98	Ye, et al.	438	710	
	A55	5	7	6	7	0	2	1	06/16/98	Imai, et al.	438	719	
	A56	5	7	8	8	7	9	9	08/04/98	Steger, et al.	156	345	
	A57	5	8	4	3	2	3	9	12/01/98	Shrotriya	134	1.1	
	A58	5	8	6	6	4	8	3	02/02/99	Shiau, et al.	438	720	
	A59	5	8	6	9	4	0	1	02/09/99	Brunemeier, et al.	438	710	
	A60	5	8	7	4	3	6	3	02/23/99	Hoh, et al.	438	721	
apple	A61	5	8	7	9	5	7	5	03/09/99	Tepman, et al.	216	68	
EXAMINER	(	<u> </u>	X1	عد	_(_		ول الم	cel	en		DATE CO	NSIDERED /	0-021
			•				_	-					

59-7)8216HEET 4 OF 5

U.S. DEPARTMENT OF COMMERCE FORM PTO-1449 ATTORNEY DOCKET NO. 4704/USA/ETCH/SILICON SERIAL NO.: N/A PATENT AND TRADEMARK OFFICE APPLICANT: Yuen, et al. LIST OF ART CITED BY APPLICANT FILING DATE: Herewith GROUP: (Use several sheets if necessary) OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.) Aydil, et al., "Multiple Steady States in a Radio Frequency Chlorine Glow Discharge," CI J. Appl. Phys., Volume 69, No. 1, January 1, 1991, pages 109-114 Hillenius, S.J., et al., "A Symmetric Submicron CMOS Technology," IEEE, pages 252-255, 1986 C2 C3 PCT Search Report dated October 28, 1999. C4 PCT Notification of International Search Report dated February 4, 1999 C5 **C**6 **C7 C8** C9 C10 C11 C12 C13 C14 C15 C16 C17 C18 C19 C20 **DATE CONSIDERED EXAMINER** EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.





~ATTORNEY DOCKET NO.:

SERIAL NUMBER:

FILING DATE:

INVENTORS:

4704/USA/ETCH/SILICON

09-718,319

N/A

HEREWITH YUEN, ET AL.

1263

EXAMINER INITIAL		PENDING U.S. PATENT APPLICATIONS
mak AV	D1	U.S. Patent Application entitled, "Method for Improved Cleaning of Substrate Processing System"; filed July 11, 1997; Serial No. 08/893,922; Inventors: Kao, et al.
000	D2	U.S. Patent Application entitled, "Apparatus for Improved Remote Microwave Plasma source for Use with Substrate Processing Systems"; filed April 23, 1997; Serial No. 08/839,111; Inventors: Kao, et al.
	D3	U.S. Patent Application entitled, "Method and Apparatus for Determining the Endpoint in a Plasma Cleaning Process"; filed July 2, 1997; Serial No. 08/887,165; Inventors: Subrahmanyam, et al.
	D4	U.S. Patent Application entitled, "Apparatus and Method for Efficient and Compact Remote Microwave Plasma Generation"; filed April 22, 1997; Serial No. 08/839,007; Inventor: Bhatnagar
	D5	U.S. Patent Application entitled, "Method and Apparatus for Pre-stabilized Plasma Generation for Microwave Clean Applications"; filed November 13, 1996; Serial No. 08/746,658; Inventors: Fong, et al.
	D6	U.S. Patent Application entitled, "Inductively Coupled HDP-CVD Reactor"; filed May 29, 1997; Serial No. 08/865,018; Inventors: Redeker, et al.
	D7	U.S. Patent Application entitled, "Symmetric Tunable Inductively Coupled HDP-CVD Reactor"; filed July 15, 1996; Serial No. 08/679,927; Inventors: Redeker, et al.
	D8	U.S. Patent Application entitled, "Apparatus and Methods for Upgraded Substrate Processing System with Microwave Plasma Source"; filed March 5, 1997; Serial No. 08/811,627; Inventors: Tanaka, et al.
0	D9	U.S. Patent Application entitled, "Microwave Apparatus for In-situ Vacuum Line Cleaning for Substrate Processing Equipment"; filed October 30, 1996; Serial No. 08/741,241; Inventors: Pang, et al.
<del>- 0 - 0</del>	D10	
	D11	
	D12	
	D13	
	D14	George Goudreau 10-021